

2SK1431

N-Channel MOS Silicon FET

Very High-Speed Switching Applications

Features

- Low ON-state resistance.
 - Very high-speed switching.
 - Converters.
 - Micaless package facilitating easy mounting.

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

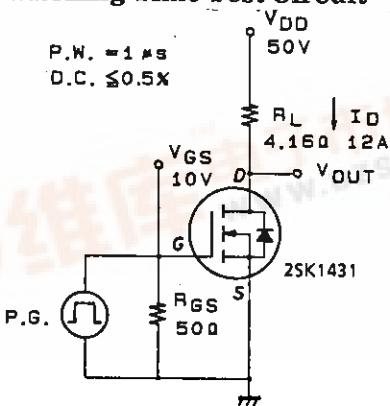
Absolute Maximum Ratings at TA = 25°C		unit
Drain to Source Voltage	V _{DSS}	100 V
Gate to Source Voltage	V _{GSS}	±20 V
Drain Current(DC)	I _D	15 A
Drain Current(Pulse)	I _{DP}	PW ≤ 10μs, duty cycle ≤ 1% 60 A
Allowable Power Dissipation	P _D	T _c = 25°C 30 W
Channel Temperature	T _{ch}	2.0 W
Storage Temperature	T _{stg}	-55 to +150 °C

Electrical Characteristics at Ta = 25°C

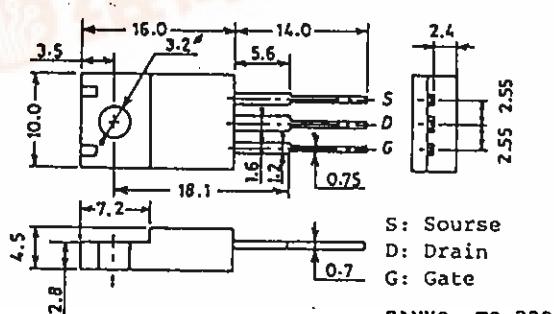
Electrical Characteristics at $T_A = 25^\circ C$		min	typ	max	unit
D-S Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 1\text{mA}, V_{GS} = 0$	100		V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 100\text{V}, V_{GS} = 0$		100	μA
Gate to Source Leakage Current	I_{GSS}	$V_{GS} = \pm 20\text{V}, V_{DS} = 0$		± 100	nA
Cutoff Voltage	$V_{GS(\text{off})}$	$V_{DS} = 10\text{V}, I_D = 1\text{mA}$	1.5	2.5	V
Forward Transfer Admittance	$ Y_{fs} $	$V_{DS} = 10\text{V}, I_D = 12\text{A}$	8.0	14	S
Static Drain to Source on State Resistance	$R_{DS(\text{on})}$	$I_D = 12\text{A}, V_{GS} = 10\text{V}$	0.075	0.10	Ω
Input Capacitance	C_{iss}	$V_{DS} = 20\text{V}, f = 1\text{MHz}$	1200		pF
Output Capacitance	C_{oss}	$V_{DS} = 20\text{V}, f = 1\text{MHz}$	350		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS} = 20\text{V}, f = 1\text{MHz}$	100		pF
Turn-ON Delay Time	$t_{d(\text{on})}$		18		ns
Rise Time	t_r	$I_D = 12\text{A}, V_{GS} = 10\text{V}$	52		ns
Turn-OFF Delay Time	$t_{d(\text{off})}$	$V_{DD} = 50\text{V}, R_{GS} = 50\Omega$	140		ns
Fall Time	t_f		70		ns
Diode Forward Voltage	V_{SD}	$I_S = 15\text{A}, V_{GS} = 0$		1.8	V

(Note) Be careful in handling the 2SK1431 because it has no protection diode between gate and source.

Switching Time Test Circuit



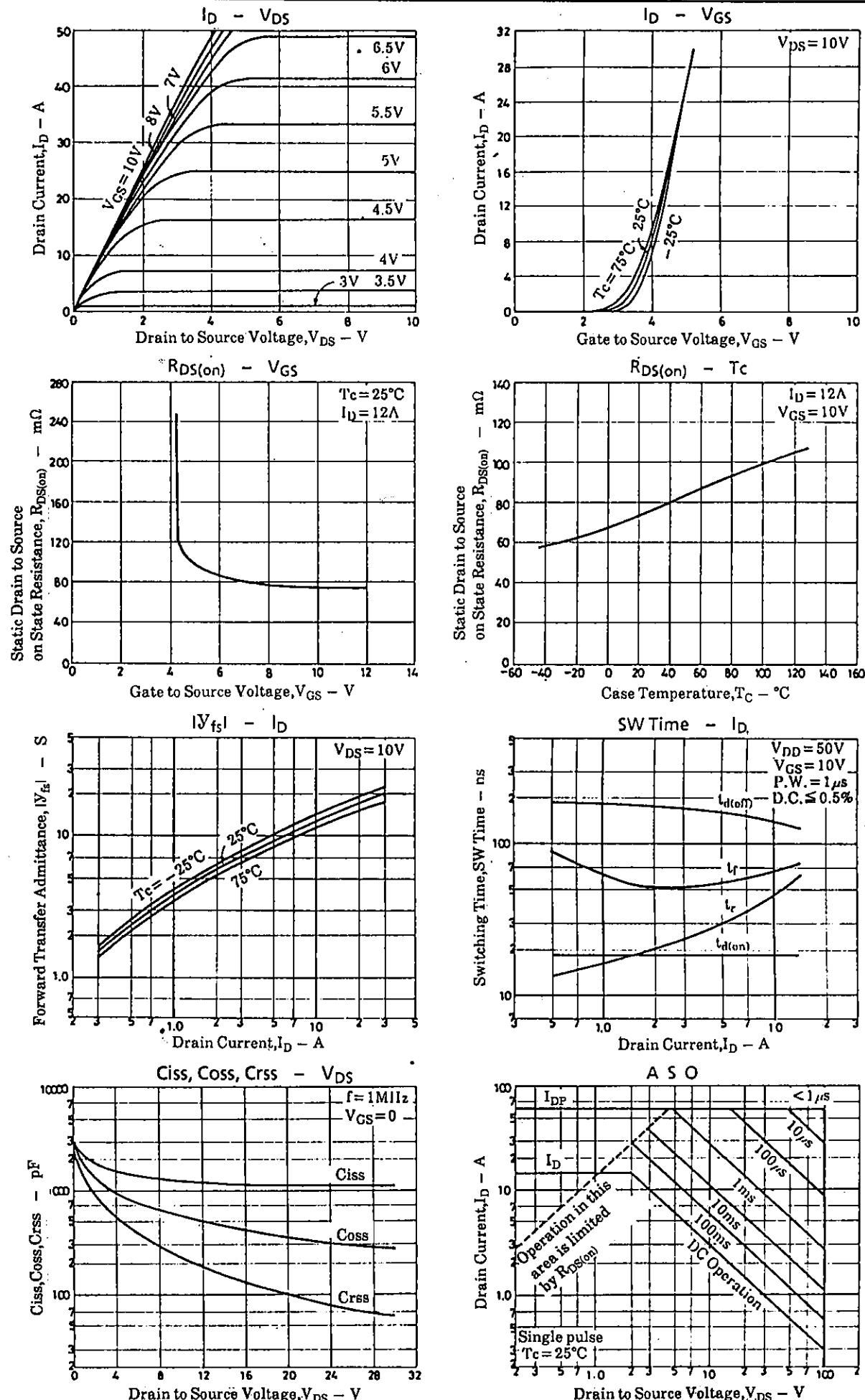
Package Dimensions 2063
(unit : mm)

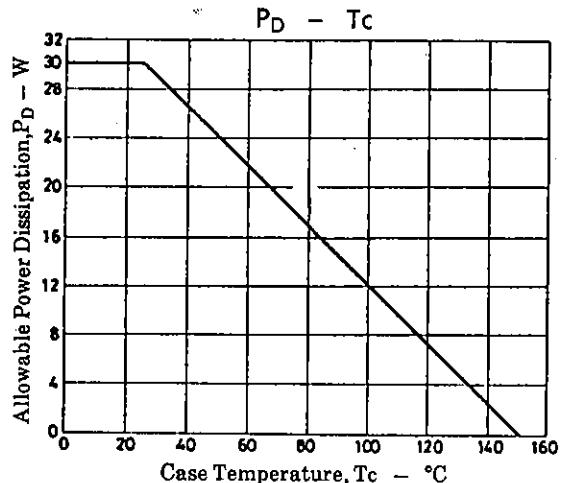
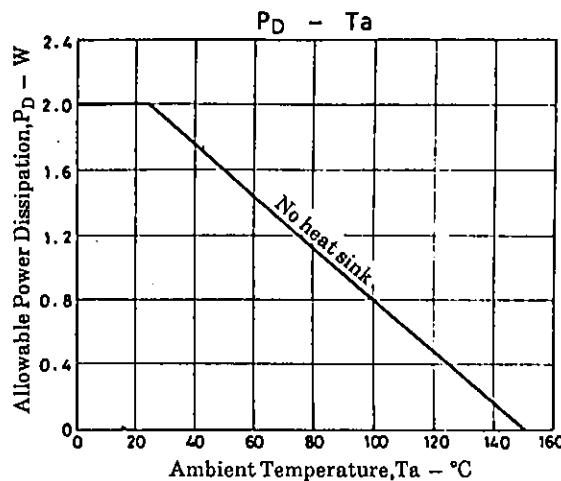
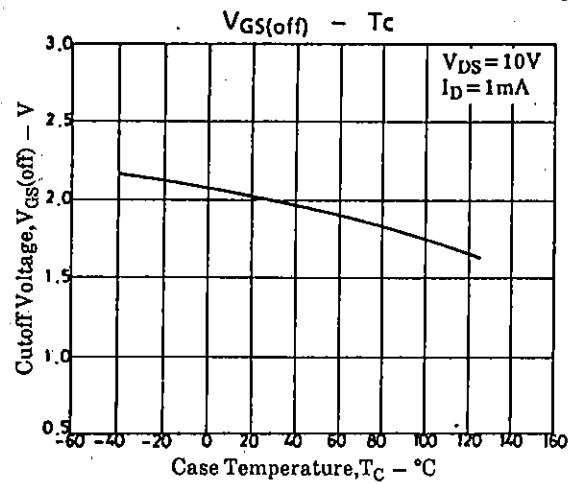


SANYO: TO-220ML



2SK1431





- No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.
- Anyone purchasing any products described or contained herein for an above-mentioned use shall:
 - ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use;
 - ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.